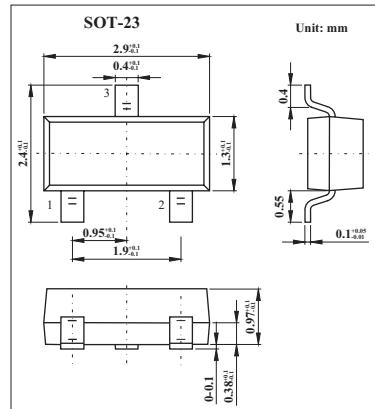


BAL74

■ Features

- Small plastic SMD package
- High switching speed:Max. 4 ns
- Continuous reverse voltage:max. 50 V
- Repetitive peak reverse voltage:max. 50 V
- Repetitive peak forward current:max. 500 mA



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	conditions	Min	Max	Unit
Repetitive peak reverse voltage	V _{RM}			50	V
Continuous reverse voltage	V _R			50	V
Continuous forward current	I _{FM}	Note 1		215	mA
Repetitive peak forward current	I _o			500	mA
Non-repetitive peak forward current	I _{FSM}	square wave; T _j = 25 °C prior to surge; t = 1 μ s t = 1ms t = 1 s		4 1 0.5	A
Total power dissipation	P _{tot}	T _{amb} 25 °C; note 1		250	mW
Storage temperature	T _{stg}		-65	+150	°C
Junction temperature	T _j			150	°C

Note

1. Device mounted on an FR4 printed-circuit board.

BAL74**■ Electrical Characteristics Ta = 25°C**

Parameter	Symbol	Test Conditions	Max	Unit
Forward voltage	VF	IF = 1 mA	715	mV
		IF = 10 mA	855	
		IF = 50 mA	1	
		IF = 150 mA	1.25	
Reverse current	IR	VR = 50 V	0.1	µ A
		VR = 50 V; Tj = 150	100	
Diode capacitance	Cd	f = 1 MHz; VR = 0;	2	pF
reverse recovery time	trr	when switched from IF = 10 mA to IR = 10 mA; RL = 100 Ω ; measured at IR = 1 mA	4	ns
forward recovery voltage	Vfr	when switched from IF = 10 mA; tr = 20ns;	1.75	V
thermal resistance from junction to tie-point	Rth j-tp		330	K/W
thermal resistance from junction to ambient	Rth j-a		500	K/W

■ Marking

Marking	JCp
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